Program: FE (All Branches)

Curriculum Scheme: Revised 2016

Examination: First Year Semester I

Course Code: FEC 102 Time: 1 hour Course Name: Applied physics I Max. Marks: 50

Note to the students:- All the Questions are compulsory and carry equal marks .

band is Si at 27°C. The band gap energy is 1.12 eV. Option A: 3.5 x 10 ⁻⁵ Option B: 6.3 x 10 ⁻⁶ Option C: 1.5 x 10⁻⁶ Option D: 5.6 x 10 ⁻⁶ Q2. Effective number of atoms for HCP is Option A: 6 Option B: 4 Option D: 1 Q3. For a particle inside a box, the potential is maximum at x = Option A: L Option B: 2L	Q1.	What is the probability of an electron being thermally excited to the conduction
Option A: 3.5×10^{-5} Option B: 6.3×10^{-6} Option C: 1.5×10^{-6} Option D: 5.6×10^{-6} Q2. Effective number of atoms for HCP is Option A: 6 Option C: 2 Option C: 2 Option D: 1 Q3. For a particle inside a box, the potential is maximum at x = Option A: L Option B: 2L		band is Si at 27°C. The band gap energy is 1.12 eV.
Option B: 6.3 x 10 ⁻⁶ Option C: 1.5 x 10⁻⁶ Option D: 5.6 x 10 ⁻⁶ Q2. Effective number of atoms for HCP is Option A: 6 Option C: 2 Option C: 2 Option D: 1 Q3. For a particle inside a box, the potential is maximum at x = Option A: L Option B: 2L	Option A:	3.5 x 10 ⁻⁵
Option C: 1.5 x 10 ⁻⁶ Option D: 5.6 x 10 ⁻⁶ Q2. Effective number of atoms for HCP is Option A: 6 Option B: 4 Option C: 2 Option D: 1 Q3. For a particle inside a box, the potential is maximum at x = Option A: L Option B: 2L	Option B:	6.3 x 10 ⁻⁶
Option D: 5.6 x 10 ⁻⁶ Q2. Effective number of atoms for HCP is Option A: 6 Option B: 4 Option C: 2 Option D: 1 Q3. For a particle inside a box, the potential is maximum at x = Option A: L Option B: 2L	Option C:	1.5 x 10 ⁻⁶
Q2.Effective number of atoms for HCP isOption A:6Option B:4Option C:2Option D:1Q3.For a particle inside a box, the potential is maximum at x =Option A:LOption B:2L	Option D:	5.6 x 10 ⁻⁶
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Option B: 4 Option C: 2 Option D: 1 Q3. For a particle inside a box, the potential is maximum at x = Option A: L Option B: 2L	Option A:	6
Option C: 2 Option D: 1 Q3. For a particle inside a box, the potential is maximum at x = Option A: L Option B: 2L	Option B:	4
Option D: 1 Q3. For a particle inside a box, the potential is maximum at x = Option A: L Option B: 2L	Option C:	2
Q3. For a particle inside a box, the potential is maximum at x = Option A: L Option B: 2L	Option D:	1
Q3. For a particle inside a box, the potential is maximum at x = Option A: L Option B: 2L		
Option A: L Option B: 2L	Q3.	For a particle inside a box, the potential is maximum at x =
Option B: 2L	Option A:	L
	Option B:	2L
Option C: L/2	Option C:	L/2
Option D: 3L	Option D:	3L
Q4. Ultrasonic waves are produced by converting	Q4.	Ultrasonic waves are produced by converting
Option A: Optical energy to sound energy	Option A:	Optical energy to sound energy
Option B: Magnetic energy to sound energy	Option B:	Magnetic energy to sound energy
Option C: Nuclear energy to sound energy	Option C:	Nuclear energy to sound energy
Option D: Mechanical energy to sound energy	Option D:	Mechanical energy to sound energy
Q5. In superconductivity, the electrical resistance of material becomes	Q5.	In superconductivity, the electrical resistance of material becomes
Option A: Zero	Option A:	Zero
Option B: Infinite	Option B:	Infinite
Option C: Finite	Option C:	Finite
Option D: All of the above	Option D:	All of the above
Q6. N-type Ge sample has donor concentration 10 ²¹ atoms/m ³ . What Hall voltage	Q6.	N-type Ge sample has donor concentration 10 ²¹ atoms/m ³ . What Hall voltage
would you expect if current of 1 mA and magnetic field 0.5T is applied across		would you expect if current of 1 mA and magnetic field 0.5T is applied across
2mm thick sample.		2mm thick sample.

Option A:	2.50 mV
Option B:	1.56mV
Option C:	3.56 mV
Option D:	9 mV
•	
Q7.	A hall of volume 6000 m ³ has a reverberation time 3 sec. if the absorbing surface
	of the hall has an area of 4000 m ³ Calculate the average coefficient of
	absorption.
Option A:	0.08 OWU
Option B:	0.06 OWU
Option C:	0.09 OWU
Option D:	0.02 OWU
08.	Determine the de-Brogile wavelength of an electron accelerated by a potential
	difference of 150 V.
Option A:	2.0056 x10 ⁻¹⁰ m
Option B:	2.5213 x10 ⁻¹⁰ m
Option C:	1.0031 x 10 ⁻¹⁰ m
Option D:	1.9068 x10 ⁻¹⁰ m
00	The temperature at which conductivity of a material becomes infinite is called
Q9.	Critical temperature
Option A:	
Option B:	Absolute temperature
Option C:	Mean temperature
Option D:	Crystallization temperature
Q10.	Sabine's formula is given by
Option A:	$T = 0.161 \times V/A$
Option B:	$T = 0.161 \times V^2 / A$
Option C:	T= 0.161 x V/A ²
Option D:	$T = 0.161 \times (V/A)^2$
Q11.	Calculate the glancing angle on the (100) plane of a rock salt crystal with lattice
	constant 2.125 A ^o for 2 nd order maximum having wavelength of incident X-ray is
	0.592 A ^o .
Option A:	$\Theta = 10.12^{\circ}$
Option B:	Θ= 16.17°
Option C:	$\Theta = 9.50^{\circ}$
Option D:	Θ = 20.18 °
Q12.	The resistivity of Cu is 1.72×10^{-8} ohm-m. Calculate the mobility of electron in
	Cu. Given the number of electrons per unit volume is $10.41 \times 10^{28} / m^3$
Option A:	3.482 x10 ⁻⁴ m ² /V-sec.
Option B:	3.482 x10 ⁻² m ² /V-sec.
Option C:	3.482 x10 ⁻³ m ² /V-sec.
Option D:	3.482 x10 ⁻⁶ m ² /V-sec.

Q13.	When is ultrasonic waves produced using piezo electric oscillator?
Option A:	At constant temperature
Option B:	At resonance
Option C:	At constant pressure
Option D:	At constant voltage
Q14.	Addition of pentavalent impurity to a semiconductor creates many
Option A:	Free electrons
Option B:	Holes
Option C:	Valence electrons
Option D:	Bound electrons
Q15.	A superconductor has a critical temperature 3.7 K at zero magnetic field . At OK
	the critical magnetic field is 0.0306 tesla . What is the critical magnetic field at
	temperature 2K?
Option A:	0.02565 Tesla
Option B:	0.01406 Tesla
Option C:	0.09651 Tesla
Option D:	0.03698Tesla
Q16.	A plane is parallel to an axis. What is its Miller Index?
Option A:	Infinity
Option B:	Zero
Option C:	One
Option D:	Finite
Q17.	Find out the lowest energy of an electron in a one dimensional box width of 4 A ^o
Option A:	3.60 eV
Option B:	2.35 eV
Option C:	1.55 eV
Option D:	4.63 eV
Q18.	Find the echo time of ultrasonic pulse travelling with velocity 5.9 x10 ³ m/sec in a
	mild steel whose correct thickness displayed by gauge meter is 1.8 mm
Option A:	5.6 μ-sec
Option B:	6.1 μ-sec
Option C:	1 μ-sec
Option D:	8 μ-sec
Q19.	Which of the following is not a characteristic of wave function?
Option A:	Continuous
Option B:	Single-valued
Option C:	Differentiable
Option D:	Physically significant

Q20.	At temperature =37°C, the energy gained by electron is = ev
Option A:	0.0267 eV
Option B:	2.67 eV
Option C:	0.267eV
Option D:	26.7eV
Q21.	Schottky defect is observed in crystals when
Option A:	some cations move from their lattice site to interstitial sites
Option B:	equal number of cations and anions are missing from the lattice
Option C:	some lattice sites are occupied by electrons
Option D:	some impurity is present in the lattice
Q22.	When the temperature of either n-type or p-type increases, determine the
	movement of the position of the Fermi energy level?
Option A:	Towards up of energy gap
Option B:	Towards down of energy gap
Option C:	Towards centre of energy gap
Option D:	Towards out of page
Q23.	An ultrasonic wave is used to detect the position of defect in a steel bar of
	thickness 50 cm. If the echo times are 40 and 90 μ -sec. locate the position of the
	defect.
Option A:	22 cm above the top surface
Option B:	22 cm below the top surface
Option C:	None of these
Option D:	22 cm middle of the top surface
Q24.	The interplaner spacing of (110) plane is 2 A ^o for a FCC crystal. Find the atomic
	radius.
Option A:	1 A ^o
Option B:	6A°
Option C:	5A°
Option D:	9 A ^o
Q25.	Which of the following materials can be used to make a light-emitting diode?
Option A:	Silicon
Option B:	Germanium
Option C:	Gallium arsenide
Option D:	Phosphorescent material